Use of Chebychev Polynomials in Thin Film Computations

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From Herpin's expression for the *m*th power of a multilayer matrix, very simple closed formulas are derived for the matrices and optical constants of any multilayer with a periodic structure.

According to Epstein's theorem, any symmetrical multilayer is equivalent to a fictitious monolayer. A simple expression for the equivalent index and thickness of this monolayer is deduced for the case of a periodic and symmetrical sequence of equally thick films.

As compared to any other method of numerical computation, the suggested formulation provides a considerable saving of time and work. In a numerical example, this saving amounts to about 80 percent.

1. Fundamental Relationships [1, 2]¹

The electromagnetic field at the plane of entry to a multilayer as in figure 1a is determined by

$$\begin{pmatrix} E_0 \\ H_0 \end{pmatrix} = \mathfrak{A}_1 \mathfrak{A}_2 \dots \mathfrak{A}_N \begin{pmatrix} 1 \\ M_s \end{pmatrix},$$

$$\mathfrak{A}_{\nu} = \begin{pmatrix} \cos B_{\nu} & \frac{i}{M_{\nu}} \sin B_{\nu} \\ iM_{\nu} \sin B_{\nu} & \cos B_{\nu} \end{pmatrix}, |\mathfrak{A}_{\nu}| = 1,$$
(1)

where

$$M_{\nu} = \frac{m_{\nu}}{\mu_{\nu}} = \frac{n_{\nu}(1-ik_{\nu})}{\mu_{\nu}}, \qquad B_{\nu} = \frac{2\pi}{\lambda} m_{\nu}d_{\nu} \cos \phi_{\nu} \quad (2)$$

are the complex index and the optical thickness in phase units of the ν th layer (n_{ν} =refractive index, k_{ν} =absorption coefficient, μ_{ν} =permeability, d_{ν} = physical thickness, λ =wavelength, and ϕ_{ν} =angle of incidence).

The amplitude transmission and reflection coefficients of the multilayer are

$$T = \frac{2M_0\sqrt{M_s + M_s^*}}{\sqrt{M_0 + M_0^*C}}, \qquad R = \frac{D}{C}$$
(3)

with

$$C = M_0 E_0 + H_0, \qquad D = M_0 E_0 - H_0. \tag{4}$$

Various methods for computing R and T have been suggested in the literature. They all have the disadvantage of being based upon recurrence relations that make it necessary to calculate the desired quantities in a cumbersome stepwise manner. Although such a procedure seems to be inevitable in



FIGURE 1: Optical multilayers.

(a) General case and denotations, (b) periodic, and (c) periodic-symmetrical multilayer. (In figures 1b and c, the individual layers a and b do not necessarily represent single films.)

general, a much simpler approach is possible with "periodic" and "periodic-symmetrical" multilayers as represented in figures 1b and c. Since such multilayers are of considerable importance in thin film work, the computation method developed hereafter is of great practical significance.

2. "Periodic" Multilayers

A multilayer in which the same sequence of films is repeated twice or more often is a "periodic" multilayer. According to Herpin's theorem [3] any multilayer, and therefore the fundamental period of layers as well, may be expressed as a fictitious bilayer the matrix of which we shall call $\mathfrak{A}_a\mathfrak{A}_b$. If the period occurs *m* times the matrix eq (1) reads

$$\binom{E_0}{H_0} = (\mathfrak{A}_a \mathfrak{A}_b)^m \binom{1}{M_s}.$$
 (5)

¹ Figures in brackets indicate the literature references at the end of this paper.

3. "Periodic-Symmetrical" Multilayers

A multilayer for which the indices and thicknesses are the same as encountered from either side,

$$\begin{pmatrix} E_0\\ H_0 \end{pmatrix} = \mathfrak{A}_{lpha}\mathfrak{A}_{lpha-1}\ldots\mathfrak{A}_2\mathfrak{A}_1\mathfrak{A}_2\ldots\mathfrak{A}_{lpha-1}\mathfrak{A}_{lpha}\begin{pmatrix} 1\\ M_s \end{pmatrix}$$

is a "symmetrical" multilayer. It can be replaced by a fictitious monolayer (Epstein [4]).

If such a multilayer consists of [m+(1/2)] times a fundamental period,

$$\begin{pmatrix} E_0 \\ H_0 \end{pmatrix} = (\mathfrak{A}_a \mathfrak{A}_b)^m \, \mathfrak{A}_a \begin{pmatrix} 1 \\ M_s \end{pmatrix}, \tag{6}$$

it is a "periodic-symmetrical" multilayer.

4. The *m*th Power of a Matrix of Unity Determinant

A simple closed expression for $(\mathfrak{A}_{a}\mathfrak{A}_{b})^{\mathrm{m}}$ is the key to eqs (5) and (6). Herpin [5] has shown that the powers of a four-element matrix can be expressed by Lucas polynomials, and Abelès [6, 1] has observed that these are reduced to Chebychev polynomials if the basic matrix is of unity determinant (which is the case for multilayer matrices). This principle, however, has not been developed further since.

Let \mathfrak{A} be any four element matrix of determinant unity and write

$$\mathfrak{A} = \begin{pmatrix} a_{11} & a_{12} \\ a_{21} & a_{22} \end{pmatrix} = a\sigma_0 + b\sigma_1 + c\sigma_2 + d\sigma_3, \quad a^2 - (b^2 + c^2 + d^2) = 1, \quad (7)$$

with

$$\sigma_{0} = \begin{pmatrix} 1 & 0 \\ 0 & 1 \end{pmatrix}, \quad \sigma_{1} = \begin{pmatrix} 0 & 1 \\ 1 & 0 \end{pmatrix}, \\ \sigma_{2} = \begin{pmatrix} 0 & -i \\ i & 0 \end{pmatrix}, \quad \sigma_{3} = \begin{pmatrix} 1 & 0 \\ 0 & -1 \end{pmatrix} \quad (8)$$

(Pauli spin matrices). Then, we obtain

$$\mathfrak{A}^2 = 2a\mathfrak{A} - \sigma_0. \tag{9}$$

Following Herpin, we set

$$\mathfrak{A}^{m} = S_{m-1} \mathfrak{A} - S_{m-2} \sigma_{0}, \qquad (10)$$

whence we arrive at

$$\mathfrak{A}^{m+1} = S_m \mathfrak{A} - S_{m-1} \sigma_0 = \mathfrak{A}^m \mathfrak{A} = S_{m-1} \mathfrak{A}^2 - S_{m-2} \mathfrak{A}$$

= $2a S_{m-1} \mathfrak{A} - S_{m-1} \sigma_0 - S_{m-2} \mathfrak{A}.$

Putting

$$2a = a_{11} + a_{22} = X, \tag{11}$$

we find by comparison of coefficients, as recurrence formula for the S_m 's,

$$S_m(X) = XS_{m-1}(X) - S_{m-2}(X).$$
 (12)

Equation (9) yields the initial values,

$$S_0(X) = 1, S_1(X) = X,$$
 (13)

and then (12) leads to

$$S_m(X) = \sum_{\mu=0}^{[m/2]} (-1)^{\mu} \binom{m}{\mu} X^{m-2\mu},$$
(14)

where [m/2] denotes the largest integer contained in m/2, e.g., [5/2]=2. Explicitly, we have

$$S_{0}=1, \\S_{1}=X, \\S_{2}=X^{2}-1, \\S_{3}=X^{3}-2X, \\S_{4}=X^{4}-3X^{2}+1, \\S_{5}=X^{5}-4X^{3}+3X, \\S_{6}=X^{6}-5X^{4}+6X^{2}-1, \\S_{7}=X^{7}-6X^{5}+10X^{3}-4X, \\S_{8}=X^{8}-7X^{6}+15X^{4}-10X^{2}+1, \\etc. \end{cases}$$
(14a)

The S_m 's defined by these equations are the Chebychev polynomials of the second kind [7],

$$S_m(X) = \frac{\sin (m+1)\Theta}{\sin \Theta}, \quad X = 2\cos \Theta, \quad (15a)$$

or

$$S_m(X) = \frac{\sinh(m+1)\Phi}{\sinh\Phi}, \qquad X = 2\cosh\Phi.$$
 (15b)

Another form is

$$S_m(X) = \frac{1}{2^{m+1}\sqrt{X^2 - 4}} \left[(X + \sqrt{X^2 - 4})^{m+1} - (X - \sqrt{X^2 - 4})^{m+1} \right].$$
(16)

For real arguments, X=x, these polynomials are also real (even though this is not obvious in eq (16) for |x| < 2). If, in eqs (15), θ and Φ are to be real for reasons of convenience, (15a) must be used for $|x| \le 2$, and (15b) for $|x| \ge 2$.

The desired matrix $(\mathfrak{A}_{a}\mathfrak{A}_{b})^{m}$ may now be obtained as follows: Form

$$\mathfrak{A}_{a}\mathfrak{A}_{b} = \begin{pmatrix} a_{11} & a_{12} \\ a_{21} & a_{22} \end{pmatrix}$$
 and $X = a_{11} + a_{22}$. (17a)

Then, find $S_{m-1}(X)$ and $S_{m-2}(X)$ and write

$$(\mathfrak{A}_{a}\mathfrak{A}_{b})^{m} = \begin{pmatrix} S_{m-1}a_{11} - S_{m-2} & S_{m-1}a_{12} \\ S_{m-2}a_{21} & S_{m-1}a_{22} - S_{m-2} \end{pmatrix} \cdot (17\mathrm{b})$$

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5. Application to Multilayers

According to (5), (6), and (17), we have

$$F_P = S_{m-1}(X) \cdot F_{ab} - S_{m-2}(X) \cdot F_s,$$
 (18)

and

$$F_{PS} = S_{m-1}(X) \cdot F_{aba} - S_{m-2}(X) \cdot F_a, \qquad (19)$$

where F stands for either field strength, E or H, and because of (4) for the quantities \tilde{C} and D as well. The subscripts P and $P\hat{S}$ refer to the whole periodic and periodic-symmetrical multilayers, respectively; the subscripts s, a, ab, and aba refer to the uncoated substrate, the bottom mono-, bi-, and trilayers, respectively.

Thus, any of these quantities can be expressed as a simple linear combination of the corresponding quantities of much simpler multilayers.

By forming the matrix product in (16), one finds the argument of the Chebychev polynomials in (18) and (19),

$$X = 2 \cos B_a \cos B_b - \frac{M_a^2 + M_b^2}{M_a M_b} \sin B_a \sin B_{b^*} (20)$$

6. Layers of Equal Thickness

The equations of section 5 are still further simplified if each film in the multilayer has the same optical thickness,

$$B_a = B_b = B. \tag{21}$$

Then, we have

$$X = 2 - \frac{(M_a + M_b)^2}{M_a M_b} \sin^2 B \cdot \tag{22}$$

While for the periodic multilayer the mathematical formulation itself is not simplified, a very simple formulation is obtained for the periodic-symmetrical multilaver:

With (21) and (22), the matrix of the trilayer (aba) can be shown to be

$$\mathfrak{A}_{a}\mathfrak{A}_{b}\mathfrak{A}_{a} = X\mathfrak{A}_{a} - \mathfrak{A}_{b}^{-1}, \qquad (23)$$

where

$$\mathfrak{A}_{b}^{-1} = \begin{pmatrix} \cos B & -\frac{i}{M_{b}} \sin B \\ -iM_{b} \sin B & \cos B \end{pmatrix}$$
(24)

is the inverse of \mathfrak{A}_{b} . Then, (17) and (12) show that

$$(\mathfrak{A}_{a}\mathfrak{A}_{b})^{m}\mathfrak{A}_{a} = S_{m}(X)\mathfrak{A}_{a} - S_{m-1}(X)\mathfrak{A}_{b}^{-1}.$$
(25)

Because of (13), (23) is contained in (25) as the particular case m=1.

Thus we see that, if all films are equally thick, it is not necessary to express the periodic-symmetrical multilayer in terms of the bottom trilayer and the | is a real number.

uncoated substrate, as in (19). Instead, it can very simply be expressed in terms of the two basic matrices \mathfrak{A}_a and \mathfrak{A}_b , without any need for multiplication of matrices whatsoever.

Epstein's theorem [4], according to which any symmetrical multilayer is equivalent to a fictitious monolayer, was already mentioned. The index M_m and the thickness B_m of the monolayer corresponding to a periodic-symmetrical multilayer with equally thick films may now be obtained as follows:

Consider (25) and write

$$(\mathfrak{A}_{a}\mathfrak{A}_{b})^{m}\mathfrak{A}_{a} = \begin{pmatrix} \cos B_{m} & \frac{i}{M_{m}}\sin B_{m} \\ iM_{m}\sin B_{m} & \cos B_{m} \end{pmatrix}.$$
(26)

Then, comparison of coefficients yields, for the thickness B_m and the index M_m of the fictitious monolaver,

$$\cos B_m = [S_m(X) - S_{m-1}(X)] \cos B, \qquad (27)$$

$$M_{m}^{2} = \frac{M_{a}S_{m}(X) + M_{b}S_{m-1}(X)}{\frac{1}{M_{a}}S_{m}(X) + \frac{1}{M_{b}}S_{m-1}(X)}$$
(28)

(According to Epstein [4], the signs of B_m and M_m have to be chosen such that $B_m \rightarrow 0$ for $\lambda \rightarrow \infty$, and that always $\operatorname{Re}(M_m) \ge 0.$)

7. Dielectric Multilayers

The above formulation constitutes a considerable simplification of practical computations.

An automatic computer can provide for itself the needed Chebychev polynomials by computing them according to eqs (14) or (16), regardless of whether X is a real or a complex number.

For desk calculations, however, numerical values of Chebychev polynomials of complex arguments cannot be found except with rather complicated calculations. This leads us to the restriction that X always should be a real number which will be true only if the multilayers are purely dielectric, and if the individual matrices \mathfrak{A}_a and \mathfrak{A}_b represent individual films. (The replacement of multilayers, even if purely dielectric, by fictitious mono- or bilayers may yield complex indices.) These assumptions lead to the important class of alternating dielectric layers, for which we have

$$M_a = m_a = n_a, \qquad M_b = m_b = n_b, \qquad (29)$$

and (for equally thick layers that are quarter wave films at a wavelength λ_0)

$$B_a = B_b = \beta = \frac{\pi}{2} \frac{\lambda_0}{\lambda} \tag{30}$$

so that

$$X = x = 2 - \frac{(n_a + n_b)^2}{n_a n_b} \sin^2 \beta$$
 (31)

For such real arguments, the Chebychev polynomials may be found with the aid of:

(a) Numerical tables: 12-decimal values of the first 12 S_m 's, for $0 \le x \le 2$ with intervals 0.001 in x, have been published by the National Bureau of Standards [7]. Jones and co-authors [8] have published similar but less complete tables. For negative arguments, find $S_m(|x|)$ and use the relation

$$S_m(-x) = (-1)^m S_m(x). \tag{32}$$

(b) Equation (15) and tables of trigonometric or hyperbolic functions: If, for instance, $S_4(3.745)$ is looked for, one finds from the table that 3.745=2 $\cosh 1.24$. Hence $\Phi = 1.24$, $5\Phi = 6.20$, and

$$S_4(3.745) = \frac{\sinh \ 6.20}{\sinh \ 1.24} = \frac{246.37}{1.58311} = 155.62.$$

(c) Direct computation: The S_m 's may also be computed from eq (14) or (16). For small values of \overline{m} it is easier to use eqs (14), but for large m's(which, however, rarely occur in multilayer work) eq (16) is faster.

8. A Practical Example

Consider a high reflection multilaver consisting of 11 alternating zinc sulfide and magnesium fluoride films on glass.

$$n_0 = 1$$
 (air), $n_a = 2.3$ (ZnS),
 $n_b = 1.38$ (MgF₂), $n_s = 1.52$ (glass).

Let all films be a quarter wave thick at $\lambda_0 = 5460.74$ A, and compute the amplitude reflection coefficient Rfor $\lambda = 4358.35$ A, i.e., for

$$\beta = \frac{\pi}{2} \frac{5460.74}{4358.35} = 112^{\circ} 45.86',$$

sin $\beta = 0.92211$, cos $\beta = -0.38694$.

Then we have according to (1), (24), and (25),

$$\begin{pmatrix} E_0 \\ H_0 \end{pmatrix} = \begin{bmatrix} S_5(x) \begin{pmatrix} -0.38694 & 0.40092i \\ 2.12085i & -0.38694 \end{pmatrix} \\ -S_4(x) \begin{pmatrix} -0.38694 & -0.66820i \\ -1.27252i & -0.38694 \end{pmatrix} \end{bmatrix} \begin{pmatrix} 1 \\ 1.52 \end{pmatrix}.$$

From (31), we obtain x = -1.62789, so that we may look up in reference [7]: $S_5(x) = 0.94004$, $S_4(x) =$ 0.07257.Thence.

 $\begin{pmatrix} E_0 \\ H_0 \end{pmatrix} \!\!=\!\! \begin{bmatrix} \begin{pmatrix} -0.36374 & 0.37688i \\ 1.99363i & -0.36374 \end{pmatrix}$ $+ \begin{pmatrix} 0.02808 & 0.04849i \\ 0.09235i & 0.02808 \end{pmatrix} \Big] \begin{pmatrix} 1 \\ 1.52 \end{pmatrix}$ $= \begin{pmatrix} -0.33566 & 0.42537i \\ 2.08603i & -0.33566 \end{pmatrix} \begin{pmatrix} 1 \\ 1.52 \end{pmatrix}$ $= \begin{pmatrix} -0.33566 + 0.64656i \\ -0.51020 + 2.08603i \end{pmatrix}$

Finally, (3) and (4) yield

$$R = \frac{0.17454 - 1.43917i}{-0.84586 + 2.73259i}$$

Starting with the given n's and with β , this result was obtained with 17 individual steps of multiplication or division and 9 steps of addition or subtraction. Four numerical values had to be looked up in tables.

In comparison hereto, it takes 96 multiplications, and 48 additions or subtractions, with 1 numerical value to be looked up, to arrive at the same result by means of the widely used recurrence method for admittances [9]. This may be estimated to be about five times as much work.

9. References

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Selected Abstracts

Measurement of the aging of rubber vulcanizates, J. Mandel, F. L. Roth, M. N. Steel, and R. D. Stiehler, J. Research NBS 63C No. 2, 141 (1959).

A study of aging data in the literature and of measurements made at the National Bureau of Standards indicates that ultimate elongation is the best of the tensile properties for characterizing the deterioration of rubber vulcanizates during storage at various temperatures. Ultimate elongation decreases during aging for all types of rubber vulcanizates; whereas, tensile strength and modulus may increase, decrease, or remain essentially unchanged. The change in ultimate elongation over prolonged periods of storage cannot be expressed by a simple mathematical equation. However, during most of the useful storage life of a rubber vulcanizate, the elongation decreases approximately linearly with the square root of time. The data indicate that for some vulcanizates an estimate of storage life at room temperature can be made from measurements of ultimate elongation at two or more elevated temperatures.

Excitation mechanisms of the oxygen 5577 emission in the upper atmosphere, E. Tandberg-Hanssen and F. E. Roach, J. Research NBS **63D** No. 3, 319 (1959).

Possible excitation mechanisms for the green 5577 emission are considered in the light of recent data on the dynamics of the upper atmosphere. Photochemical reactions as affected by mass motions as well as excitation directly due to the mass motions are analyzed.

Method for measuring local electron density from an artifical satellite L. R. O. Storey, J. Research NBS 63D No. 3, 325 (1959).

A method is proposed for measuring the electron density at known points in the outer ionosphere, by the use of vlf receiving equipment in an artificial satellite, in conjunction with a vlf transmitter on the ground. The transmitter would radiate continuous waves, which would be propagated through the ionosphere in the 'whistler' mode. The basis of the method is a measurement of the local wave admittance of the medium, by comparison of the signals received on an electric dipole and on a loop.

A further proposal is made for an integrated vlf satellite experiment, in which several different types of observation would be made simultaneously.

Reflectors for a microwave Fabry-Perot interferometer W. Culshaw, *IRE Trans. on Microwave Theory and Techniques*, Vol. **MTT-7**, No. 2, 221 (1959).

The advantages of microwave interferometers for wavelength and other measurements at millimeter wavelengths are indicated, and a microwave Fabry-Perot interferometer discussed in detail. Analogous to the cavity resonator, this requires reflectors of high reflectivity, small absorption, and adequate size. Stacked dielectric plates, and stacked planar or rod gratings are shown to be suitable forms of reflectors, and equations for the reflectivity, optimum spacing, and bandwidth of such structures are derived. A series of stacked metal plates with regularly spaced holes represents a good design of reflector for very small wavelengths. Fringes and wavelength measurements at 8-mm wavelength are given for one design of interferometer, these being accurate to 1 in 10^{4} without any diffraction correction. For larger apertures and reflectors in terms of the wavelength, errors due to diffraction will decrease.

The nature, cause, and effect of the porosity in electrodeposits, III. Microscopic detection of porosity, F. Ogburn and D. W. Ernst, *Plating* **46**, 831 (1959).

A new technique called "parallel sectioning" was used for investigating the porosity of nickel electrodeposits. Some of the coating is polished off in a layer parallel to the basis metal. After taking a photomicrograph of this area, another layer of metal is removed. This procedure is continued until the basis metal has been reached. It is possible to construct a three-dimensional model of the coating. Various pore types are listed and illustrative photomicrographs are given.

Mechanism of contraction in the muscle fiber-ATP system, L. Mandelkern, A. S. Posner, A. F. Diorio, and K. Laki, *Proc. Nat. Acad. Sci. U.S.* 45, No. 6, 814 (1959).

The axial contraction that develops when glycerol-treated rabbit psoas muscle was immersed in ATP solutions of varying concentrations was measured. The length-concentration diagram has the characteristics typical of a cooperative phase transformation and the shrinkage can be attributed to melting of the initially axially oriented polypeptide chains. This conclusion was substantiated by wide angle x-ray diffraction studies of the native and shrunken fibers which show the structural changes expected on melting. Thus, the same principles that govern the contractile processes in a wide variety of fibrous macromolecular systems are also operative in the muscle-ATP system.

Microwave spectrum of methyl germane, V. W. Laurie, J. Chem. Phys. 30, No. 5, 1210 (1959).

The $J=0\rightarrow 1$ and $1\rightarrow 2$ transitions of 28 isotopic species of CH_3GeH_3 have been measured. From the rotational constants obtained, the following structural parameters have been calculated: $r_{CH}=1.083\pm 0.005 \, \text{A}^\circ$, $r_{GeH}=1.529\pm 0.005 \, \text{A}^\circ$, $r_{CGe}=1.9453\pm 0.0005 \, \text{A}^\circ$, χ HCH=108°25′±30′, χ HGeH=109°15′±30′. The K=1 transitions of the asymmetrically deuterated species are split by internal rotation about the C—Ge bond. With the assumption of a threefold sinusoidal potential, an internal barrier of 1239 ± 25 cal/mole has been determined from these splittings. Analysis of the Stark effect of several species gives a dipole moment of 0.635 ± 0.006 D. From observed hyperfine structure the nuclear quadrupole coupling constant of Ge⁷³ has been calculated to be $+3 \, \text{Mc}$.

Measurement of ozone in terms of its optical absorption, R. Stair, Advances in Chem. Series of the Am. Chem. Soc., No. 21, 269 (1959).

The unique absorption spectrum of ozone provides an ideal physical basis for measuring its concentration in the atmosphere even in the presence of significant quantities of other atmospheric pollutants, whether of gaseous or particulate character. Various types of optical equipment have been considered, both for measurement of the total amount of ozone and for determination of its vertical distribution and horizontal concentration. Natural sunlight furnishes a suitable and convenient light source for measuring the total amount and vertical distribution of ozone. Special sources having high radiant intensity within the spectral region of 2500 to 3600 A, where ozone has a high optical absorption, are desired for use in measuring the horizontal concentration of ozone. The light source, whether the sun or some special source such as a mercury arc lamp, may be employed with a simple filter radiometer or with a more or less elaborate prism or grating spectroradiometer as desired. In most of the recent work at the National Bureau of Standards a double, quartz prism spectroradiometer has been used at Washington, D.C., Climax, Colo, Los Angeles, Calif., and Sunspot, N. Mex., in ozone studies.

Lower bounds for eigenvalues with application to the helium atom, N. W. Bazley, *Proc. Nat. Acad. Sci. U.S.* **45**, *No.* 6, 850 (1959).

Let A be a self-adjoint operator with domain D in a Hilbert space \mathfrak{H} . Suppose $A = A' + \overline{A}$ where \overline{A} is self-adjoint and A' is positive definite. The eigenvalue problem for \overline{A} , whose solution we assume known, gives rough lower bounds. If $\overline{u_i}$ $(i=1,\ldots,k)$ are k discrete eigenvectors of \overline{A} and if $P_i =$ $(A')^{-1}\overline{u_i}$ $(i=1,\ldots,k)$ exist then one can substantially improve the lower bounds. The theory is applied to the helium atom operator.

Spectroscopic evidence for triatomic nitrogen in solids at very low temperature, M. Peyron, E. M. Horl, H. W. Brown, and H. P. Broida, J. Chem. Phys. 30, No. 5, 1304 (1959).

Additional wavelength, intensity and lifetime measurements of the radiation emitted from solid nitrogen containing trapped atoms have led to the interpretation that a weakly bound triatomic molecule, N_2-N , is an emitting species. The three lowest electronic levels of atonic nitrogen ²P, ²D, and ⁴S are involved in the eight line groups which have been found. Isotopic substitution has confirmed this model. Evidence also has been found for an N_2-O molecule similar to the N_2-N .

Thermodynamic properties of helium at low temperatures and high pressures. D. B. Mann and R. B. Stewart, NBS Tech. Note 8 (PB151367) \$1.25.

This is a compilation and correlation of the present data on the thermodynamic properties of helium below 20° K. The existing (best) values are selected. The results are presented in the form of temperature-entropy and enthalpy-entropy diagrams. Pressures to 100 atm, temperatures from 0° K to 20° K and specific volumes from 5 liters/kg to 800 liters/kg are presented.

On the perturbation of the vibrational equilibrium distribution of reactant molecules by chemical reactions, K. E. Shuler, 7th Symp. (Intern.) on Combustion, London and Oxford, Aug. 28 to Sept. 3, 1958, Combustion Inst. p. 87 (Butterworths Sci. Pub., London, England, 1958).

A mathematical analysis is made of the stepwise excitation of an assembly of harmonic oscillators with an irreversible dissociation limit by a solution of the transport equations using Gottlieb polynomials. The variations in the distribution function as determined by values of the dissociation energy and the conditions for perturbation of the equilbrium Boltzmann vibrational distribution because of chemical reactions are discussed.

Other NBS Publications*

Journal of Research, Section 63B, No. 2, October-December 1959. 75 cents.

- Applications of a theorem on partitioned matrices. E. V. Haynsworth.
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- Evaluation of lens distortion by the modified goniometric method. Francis E. Washer and Walter R. Darling.
- Proposed criteria for defining load failure of beams, floors, and roof constructions during fire tests. J. V. Ryan and A. F. Robertson.
- Conductive flooring for hospital operating rooms. Thomas H. Boone, Francis L. Hermach, Edgar H. MacArthur, and Rita C. McAuliff.
- Measurement of the aging of rubber vulcanizates. J. Mandel, F. L. Roth, M. N. Steel, and R. D. Stiehler. (See above abstracts.)

Journal of Research, Section 63D, No. 3, November—December 1959. 70 cents.

- Radio-refractive-index climate near the ground. B. R. Bean and J. D. Horn.
- Path antenna gain in an exponential atmosphere. W. J. Hartman and R. E. Wilkerson,
- Effect of atmospheric horizontal inhomogeneity upon ray tracing. B. R. Bean and B. A. Cahoon.
- Correlation of solar noise fluctuations in harmonically related bands. L. R. O. Storey.
- A monochromatic low-latitude aurora. F. E. Roach and E. Marovich.
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